

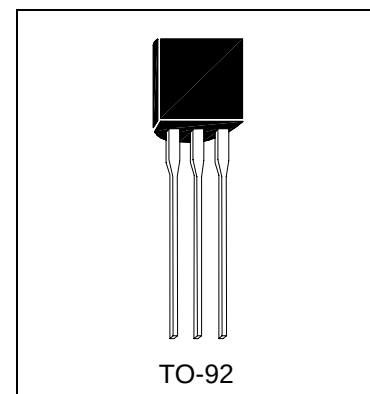


HE9018

NPN EPITAXIAL PLANAR TRANSISTOR

Description

The HE9018 is designed for use in AM/FM if amplifier and local oscillator of FM/VHF tuner.



Absolute Maximum Ratings

- Maximum Temperatures
Storage Temperature -55 °C +150 °C
Junction Temperature +150 °C Maximum
- Maximum Power Dissipation
Total Power Dissipation ($T_A=25^{\circ}\text{C}$) 625 mW
- Maximum Voltages and Currents ($T_A=25^{\circ}\text{C}$)
 V_{CBO} Collector to Base Voltage 30 V
 V_{CEO} Collector to Emitter Voltage 15 V
 V_{EBO} Emitter to Base Voltage 5 V
 I_C Collector Current 50 mA
 I_B Base Current 10 mA

Electrical Characteristics ($T_A=25^{\circ}\text{C}$)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV_{CBO}	30	-	-	V	$I_C=100\mu\text{A}$
BV_{CEO}	15	-	-	V	$I_C=1\text{mA}$
BV_{EBO}	5	-	-	V	$I_E=100\mu\text{A}$
I_{CBO}	-	-	50	nA	$V_{CB}=12\text{V}$
$*V_{CE(sat)}$	-	-	0.5	V	$I_C=10\text{mA}$, $I_B=1\text{mA}$
$*h_{FE}$	39	-	198		$V_{CE}=5\text{V}$, $I_C=1\text{mA}$
f_T	700	1100	-	MHz	$V_{CE}=5\text{V}$, $I_C=5\text{mA}$
Cob	-	1.3	1.7	pF	$V_{CB}=10\text{V}$, $I_E=0$

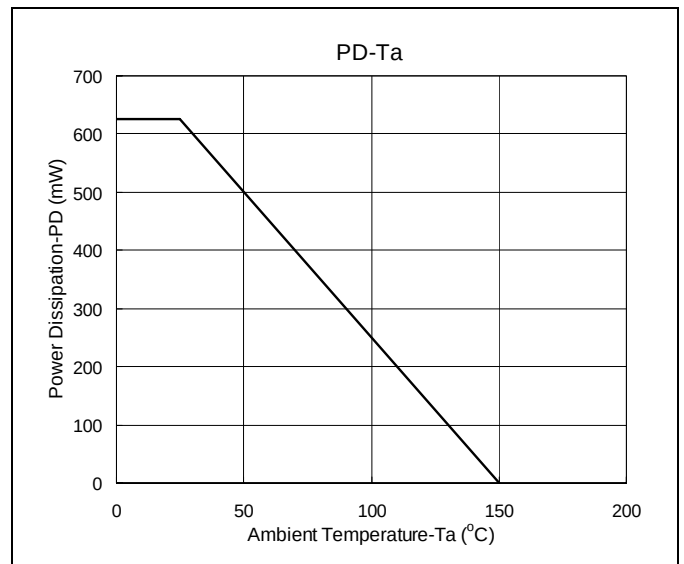
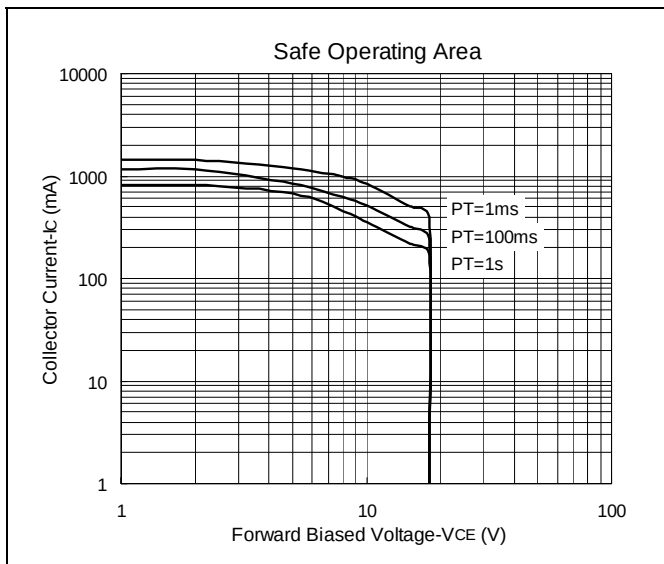
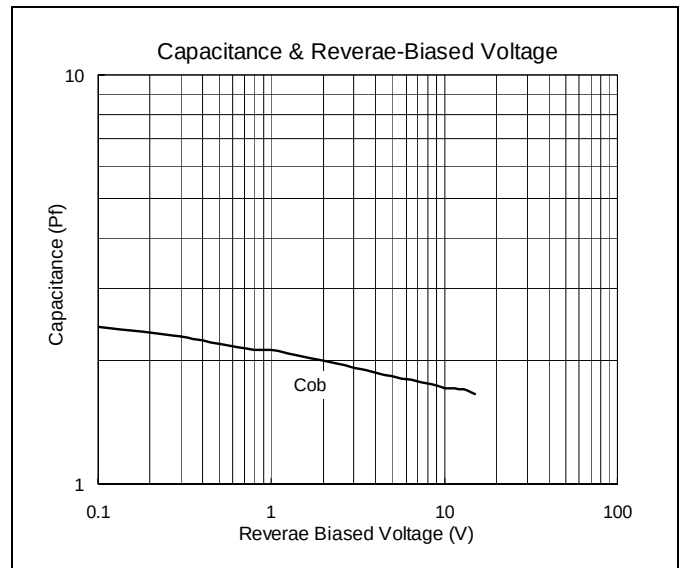
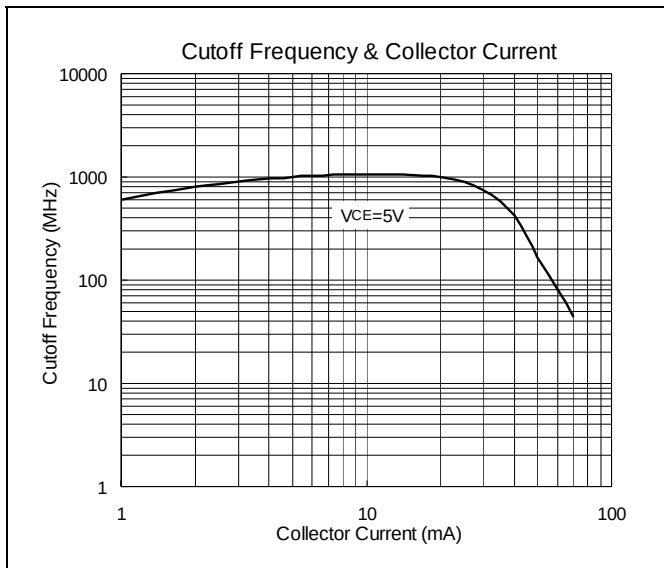
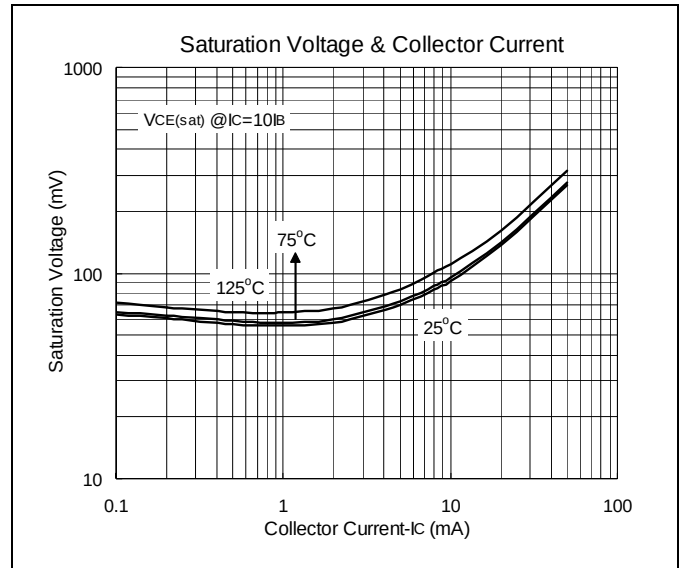
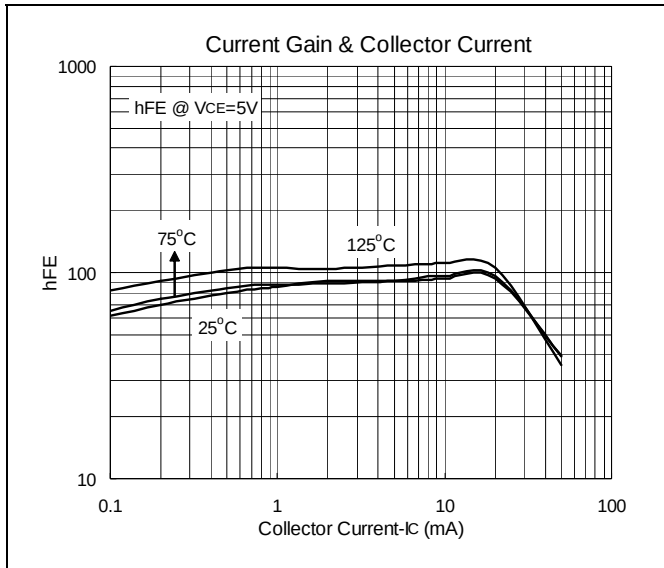
*Pulse Test: Pulse Width $\leq 380\mu\text{s}$, Duty Cycle $\leq 2\%$

Classification on hFE

Rank	E	F	G	H	I
Range	39-60	54-80	72-108	97-146	132-198

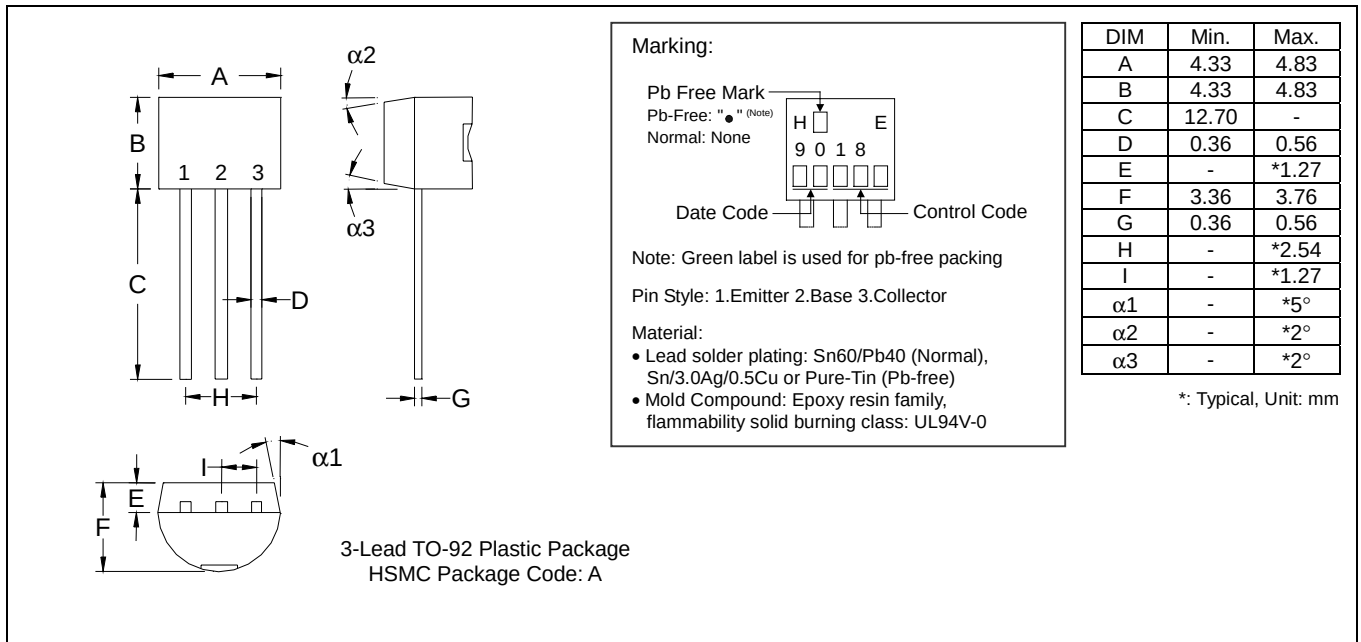


Characteristics Curve

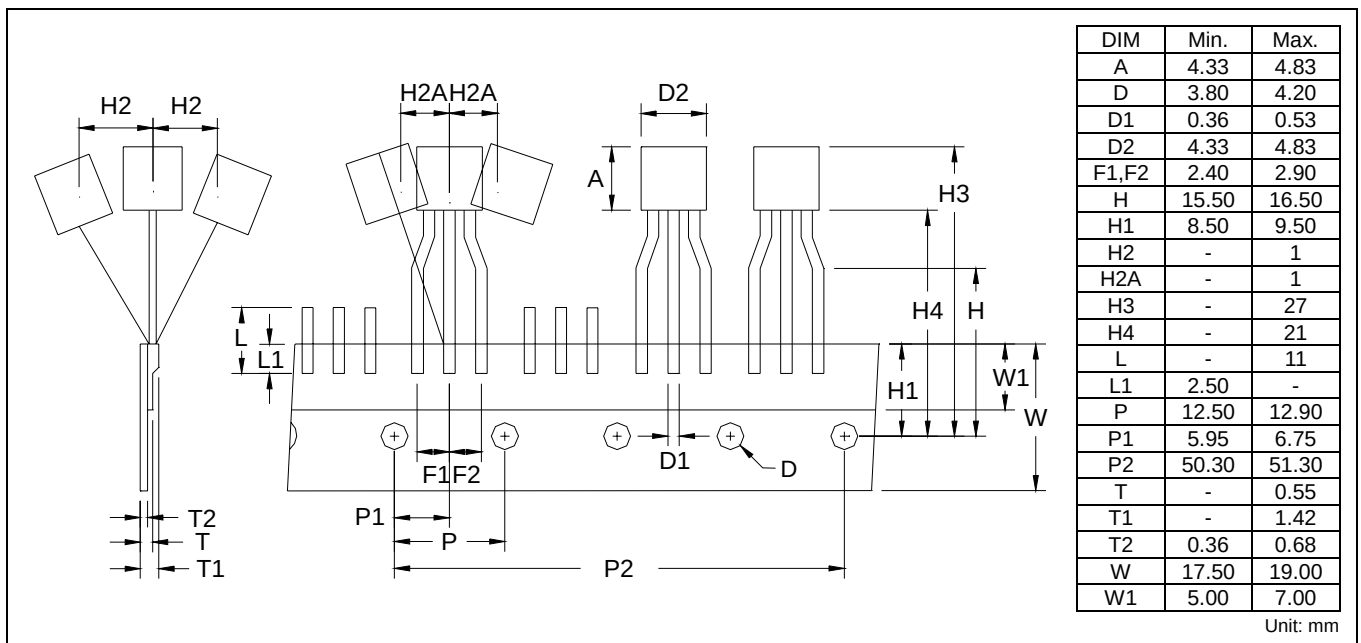




TO-92 Dimension



TO-92 Taping Dimension



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Head Office And Factory:

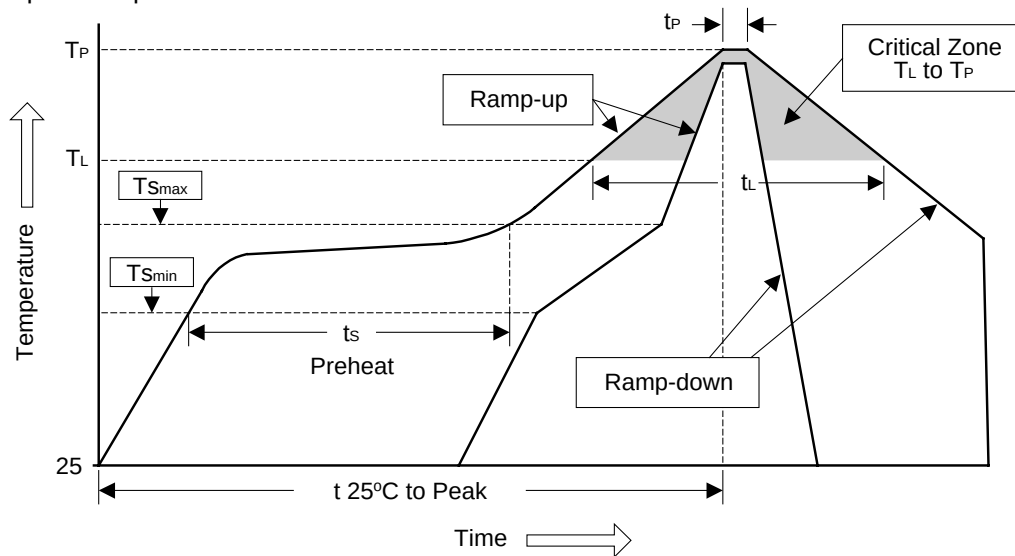
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Soldering Methods for HSMC's Products

1. Storage environment: Temperature=10°C~35°C Humidity=65%±15%
2. Reflow soldering of surface-mount devices

Figure 1: Temperature profile



Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T_L to T_P)	<3°C/sec	<3°C/sec
Preheat		
- Temperature Min (T_{smin})	100°C	150°C
- Temperature Max (T_{smax})	150°C	200°C
- Time (min to max) (t_s)	60~120 sec	60~180 sec
T_{smax} to T_L		
- Ramp-up Rate	<3°C/sec	<3°C/sec
Time maintained above:		
- Temperature (T_L)	183°C	217°C
- Time (t_L)	60~150 sec	60~150 sec
Peak Temperature (T_P)	240°C +0/-5°C	260°C +0/-5°C
Time within 5°C of actual Peak Temperature (t_P)	10~30 sec	20~40 sec
Ramp-down Rate	<6°C/sec	<6°C/sec
Time 25°C to Peak Temperature	<6 minutes	<8 minutes

3. Flow (wave) soldering (solder dipping)

Products	Peak temperature	Dipping time
Pb devices.	245°C ±5°C	5sec ±1sec
Pb-Free devices.	260°C +0/-5°C	5sec ±1sec